

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	1	"10/575853"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/21 15:13
S2	285	(light adj emitting) and III-V and transparent and (band adj gap) and (etch or etched) and dopant	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/21 15:25
S3	10134	(257/79,86,98,101,102,103.ccls. 438/22,37,936.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/21 15:30
S4	94	S2 and S3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/21 15:30
S5	10451	(257/79,86,96,98,101,102,103.ccls. 438/22,37,936.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/21 15:34
S6	100	S5 and S2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/21 15:34
S7	100	S5 and S2 and (AlGaInP or GaP or GaAsP or AlGaAs)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/21 15:34
S8	100	S5 and S2 and (AlGaInP or GaP)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/21 15:35
S9	285	(light adj emitting) and III-V and transparent and (band adj gap) and (etch or etched) and dopant	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 11:03
S10	10469	(257/79,86,96,98,101,102,103.ccls. 438/22,37,936.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 11:03

S11	100	(S10 and S9) and (AlGaInP or GaP)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 11:03
S12	1	"10/575853"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 11:13
S13	463	(light adj emitting) and III-V and transparent and (band adj gap) and (etch or etched) and (dopant or doped)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 11:20
S14	162	S13 and S10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 11:21
S15	162	S14 and (AlGaInP or GaP or GaAsP or AlGaAs)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 11:22
S16	10469	(257/79,86,96,98,101,102,103.ccls. 438/22,37,936.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 13:48
S17	463	(light adj emitting) and III-V and transparent and (band adj gap) and (etch or etched) and (dopant or doped)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 13:48
S18	162	(S17 and S16) and (AlGaInP or GaP or GaAsP or AlGaAs)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 13:48
S19	37	(S17 and S16) and (AlGaInP or GaP or GaAsP or AlGaAs) and (transparent same etched)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 13:51
S20	14	(S17 and S16) and (AlGaInP or GaP or GaAsP or AlGaAs) and (transparent same etched same side)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 13:53
S21	6	(S17 and S16) and (AlGaInP or GaP or GaAsP or AlGaAs) and (transparent same etched with side))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 13:54

S22	3	(S17 and S16) and (AlGaInP or GaP or GaAsP or AlGaAs) and ((etchedd with side same (damaged or damage))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 14:39
S23	304	(AlGaInP or GaP or GaAsP or AlGaAs) and ((etched with side) same (damaged or damage))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 14:44
S24	30	S23 and S16	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 14:44
S25	21	S23 and S16 and (doped or doping or concentration)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 14:44
S26	30	(S17 and S16) and (AlGaInP or GaP or GaAsP or AlGaAs) and (dope\$1 with (transparent or window))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/27 16:19
S27	2940	(GaP same ((light adj emitting) or LED)) and (GaP same (dopant or doping or concentration or cm))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/28 11:23
S28	313	(GaP same ((light adj emitting) or LED)) and (GaP same (dopant or doping or concentration or cm)) and (AlGaInP or GaInAlP or GaAlInP)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/28 11:24
S29	10469	(257/79,86,96,98,101,102,103.ccls. 438/22,37,936.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/28 11:24
S30	165	S28 and S29	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/28 11:24
S31	313	("GaP" same ((light adj emitting) or LED)) and ("GaP" same (dopant or doping or concentration or cm)) and (AlGaInP or GaInAlP or GaAlInP)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/28 11:25
S32	165	S31 and S29	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/28 11:25

S33	67	S31 and S29 and ((dopant or doping) with concentration)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/28 11:30
S34	37	S31 and S29 and (((dopant or doping) with concentration) same "GaP")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/28 11:31
S35	6	S31 and S29 and (((dopant or doping) with concentration) same "GaP" same window)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/28 12:29
S36	285	((light adj emitting) and III-V and transparent and (band adj gap) and (etch or etched) and dopant	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/30 00:22
S37	3	(aqueous adj sulfuric adj acid) with (hydrogen adj peroxide) and S36	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/30 00:22
S38	15	(aqueous adj sulfuric adj acid) with (hydrogen adj peroxide) and GaP and (etch or etching)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/24 14:50
S39	8	(aqueous adj sulfuric adj acid) with (hydrogen adj peroxide) and GaP and (etch or etching) and (damage or damaged)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/24 14:56
S40	10721	(257/79,86,96,98,101,102,103.ccls. 438/22,37,936.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/24 15:19
S41	322	("GaP" same ((light adj emitting) or LED)) and ("GaP" same (dopant or doping or concentration or cm)) and (AlGaInP or GaInAlP or GaAlInP)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/24 15:19
S42	6	S41 and S40 and (((dopant or doping) with concentration) same "GaP" same window)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/24 15:19
S43	11357	(257/79,86,96,98,101,102,103,E33.001.ccls. 438/22,37,936.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/14 16:08

S44	504	((light adj emitting) and III-V and transparent and (band adj gap) and (etch or etched) and (dopant or doped)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/14 16:08
S45	14	(S44 and S43) and (AlGaInP or GaP or GaAsP or AlGaAs) and (transparent same etched same side)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/14 16:08
S46	3	((S44 and S43) and (AlGaInP or GaP or GaAsP or AlGaAs) and ((etched with side) same (damaged or damage))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/14 16:09
S47	344	(AlGaInP or GaP or GaAsP or AlGaAs) and ((etched with side) same (damaged or damage))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/14 16:09
S48	21	S47 and S43 and (doped or doping or concentration)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/14 16:09
S49	336	("GaP" same ((light adj emitting) or LED)) and ("GaP" same (dopant or doping or concentration or cm)) and (AlGaInP or GaInAlP or GaAlInP)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/14 16:09
S50	6	S49 and S43 and (((dopant or doping) with concentration) same "GaP" same window)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/14 16:09
S51	39	S45 S48 S50	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/14 16:09
S52	35	S51 and (etch or etched)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/14 16:11
S53	1	((light and emitting and III-V and transparent and thickness and band and gap and quantum and peak and wavelength and etched and dopant and concentration).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/14 16:36

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